

Thyristors

8 Amp Sensitive, Standard & Alternistor (High Commutation) Triacs

Absolute Maximum Ratings — Sensitive Triac (4 Quadrants)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	Lxx08Ly Lxx08Ry / Lxx08Vy / Lxx08Dy	$T_c = 80^\circ\text{C}$ $T_c = 85^\circ\text{C}$	8	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	f = 50 Hz f = 60 Hz	t = 20 ms t = 16.7 ms	65 85	A
I^2t	I^2t Value for fusing		$t_p = 8.3 \text{ ms}$	26.5	A^2s
di/dt	Critical rate of rise of on-state current $I_G = 50\text{mA}$ with 0.1μs rise time	f = 120 Hz	$T_j = 110^\circ\text{C}$	70	$\text{A}/\mu\text{s}$
I_{GTM}	Peak gate trigger current	$t_p = 20\mu\text{s}$	$T_j = 110^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 110^\circ\text{C}$	0.4	W
T_{stg}	Storage temperature range			-40 to 150	°C
T_j	Operating junction temperature range			-40 to 110	°C

Note: xx = voltage/10, y = sensitivity

Absolute Maximum Ratings — Standard Triac

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	Qxx08Ry / Qxx08Ny Qxx08Ly	$T_c = 95^\circ\text{C}$ $T_c = 90^\circ\text{C}$	8	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	f = 50 Hz f = 60 Hz	t = 20 ms t = 16.7 ms	83 100	A
I^2t	I^2t Value for fusing		$t_p = 8.3 \text{ ms}$	41	A^2s
di/dt	Critical rate of rise of on-state current $I_G = 200\text{mA}$ with ≤ 0.1μs rise time	f = 120 Hz	$T_j = 125^\circ\text{C}$	70	$\text{A}/\mu\text{s}$
I_{GTM}	Peak gate trigger current	$t_p = 20\mu\text{s}$	$T_j = 125^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation	-	$T_j = 125^\circ\text{C}$	0.5	W
T_{stg}	Storage temperature range	-	-	-40 to 150	°C
T_j	Operating junction temperature range	-	-	-40 to 125	°C

Note: xx = voltage/10, y = sensitivity

Absolute Maximum Ratings — Alternistor (3 Quadrants)						
Symbol	Parameter				Value	Unit
I_{TRMS}	RMS on-state current (full sine wave)		Qxx08LHy Qxx08RH _y / Qxx08NH _y Qxx08VHy / Qxx08DH _y	$T_c = 90^\circ\text{C}$ $T_c = 95^\circ\text{C}$	8	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	f = 50 Hz	t = 20 ms	Qxx08VHy / Qxx08DH _y Qxx08LHy / Qxx08RH _y / Qxx08NH _y Qxx08VHy / Qxx08DH _y	80 83 85	A
		f = 60 Hz	t = 16.7 ms	Qxx08LHy / Qxx08RH _y / Qxx08NH _y	100	
I^2t	I^2t Value for fusing		$t_p = 8.3 \text{ ms}$	Qxx08VHy / Qxx08DH _y Qxx08LHy / Qxx08RH _y / Qxx08NH _y	30 41	A ² s
di/dt	Critical rate of rise of on-state current		f = 120 Hz	$T_j = 125^\circ\text{C}$	70	A/ μ s
I_{GTM}	Peak gate trigger current	$t_p = 20 \mu\text{s}$		$T_j = 125^\circ\text{C}$	Qxx08VHy / Qxx08DH _y Qxx08LHy / Qxx08RH _y / Qxx08NH _y	4 4
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ\text{C}$	$I_{GT} = 10 \text{ mA}$ $I_{GT} = 35 \text{ mA}$	Qxx08VHy / Qxx08DH _y Qxx08LHy / Qxx08RH _y / Qxx08NH _y	0.4 0.5
T_{stg}	Storage temperature range				-	-40 to 150 °C
T_j	Operating junction temperature range				-	-40 to 125 °C

Note: xx = voltage/10, y = sensitivity

Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified) — Sensitive Triac (4 Quadrants)						
Symbol	Test Conditions	Quadrant		Lxx08x6	Lxx08x8	Unit
I_{GT}	$V_D = 12 \text{ V}$ $R_L = 60 \Omega$	I - II - III IV	MAX.	5 10	10 20	mA
V_{GT}	$V_D = 12 \text{ V}$ $R_L = 60 \Omega$	ALL	MAX.		1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 110^\circ\text{C}$	ALL	MIN.		0.2	V
I_H	$I_T = 100 \text{ mA}$		MAX.	10	20	mA
dv/dt	$V_D = V_{DRM}$ Gate Open $T_j = 100^\circ\text{C}$	400V 600V	TYP.	30 20	40 30	V/ μ s
$(dv/dt)c$	$(di/dt)c = 4.3 \text{ A/ms}$ $T_j = 110^\circ\text{C}$		TYP.	2	2	V/ μ s
t_{gt}	$I_G = 100 \text{ mA}$ $PW = 15 \mu\text{s}$ $I_T = 11.3 \text{ A(pk)}$		TYP.	3.0	3.2	μ s

Note: xx = voltage/10, x = package, y = sensitivity

Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified) — Standard Triac

Symbol	Test Conditions	Quadrant		Qxx08x4	Qxx08x5	Unit
I_{GT}	$V_D = 12V$ $R_L = 60 \Omega$	I - II - III IV	MAX. TYP.	25 50	50 75	mA
V_{GT}	$V_D = 12V$ $R_L = 60 \Omega$	I - II - III	MAX.		1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 k\Omega$ $T_j = 125^\circ\text{C}$	ALL	MIN.		0.2	V
I_H	$I_T = 200\text{mA}$		MAX.	50	50	mA
dv/dt	$V_D = V_{DRM}$ Gate Open $T_j = 125^\circ\text{C}$	400V		150	-	
		600V		-	125	
		800V	MIN.	-	100	V/ μs
		1000V		-	80	
(dv/dt)c	(di/dt)c = 4.3 A/ms $T_j = 125^\circ\text{C}$		TYP.	4	4	V/ μs
t_{gt}	$I_G = 100\text{mA}$ PW = 15 μs $I_T = 11.3 \text{A(pk)}$		TYP.	3.0	3.0	μs

Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified) — Alternistor Triac (3 Quadrants)

Symbol	Test Conditions	Quadrant		Qxx08xH3	Qxx08xH4	Unit
I_{GT}	$V_D = 12V$ $R_L = 60 \Omega$	I - II - III	MAX.	-	10	35
V_{GT}	$V_D = 12V$ $R_L = 60 \Omega$	I - II - III	MAX.		1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 k\Omega$ $T_j = 125^\circ\text{C}$	I - II - III	MIN.	-	0.2	V
I_H	$I_T = 100\text{mA}$		MAX.	-	15	mA
dv/dt	$V_D = V_{DRM}$ Gate Open $T_j = 125^\circ\text{C}$	Qxx08LHy / Qxx08RHy / Qxx08NHy	MIN.	400V	75	400
				600V	50	300
				800V		200
				1000V		100
		Qxx08VHy / Qxx08DHy		400V	75	450
				600V	50	350
				800V		250
				1000V		150
(dv/dt)c	(di/dt)c = 4.3 A/ms $T_j = 125^\circ\text{C}$	MIN.	-	20	25	V/ μs
t_{gt}	$I_G = 100\text{mA}$ PW = 15 μs $I_T = 11.3 \text{A(pk)}$	TYP.	-	4.0	4.0	μs

Note: xx = voltage/10, x = package, y = sensitivity

Static Characteristics

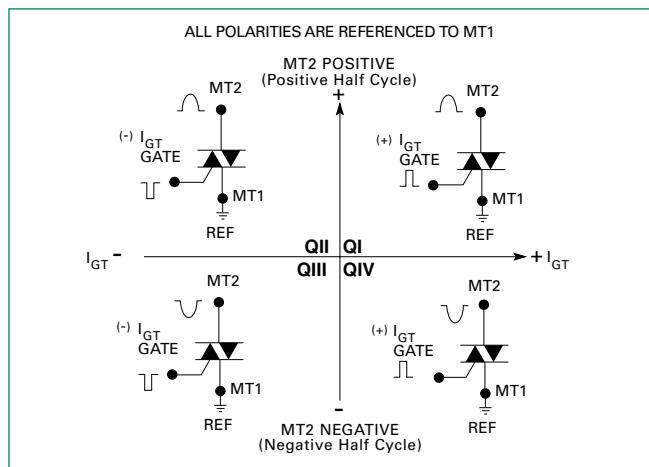
Symbol	Test Conditions				Value	Unit	
V_{TM}	$V_{DRM} = V_{RRM}$	$I_{TM} = 11.3A$	$t_p = 380 \mu s$		MAX.	1.60	V
I_{DRM}		Lxx08xy	$T_J = 25^\circ C$		10	μA	
			$T_J = 110^\circ C$		0.5	mA	
		Qxx08xy	$T_J = 25^\circ C$		20	μA	
			$T_J = 125^\circ C$		2	mA	
			$T_J = 100^\circ C$		3	mA	
I_{RRM}			$T_J = 25^\circ C$		10	μA	
			$T_J = 100^\circ C$		20	μA	
		Qxx08xHy	$T_J = 125^\circ C$		2	mA	
			$T_J = 100^\circ C$		3	mA	

Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	L/Qxx08Ryy / L/Qxx08Nyy	1.5
		L/Qxx08Lyy	2.8
		L/Qxx08Vyy	2.1
$R_{\theta(J-A)}$	Junction to ambient	L/Qxx08Ryy	45
		L/Qxx08Lyy	50
		L/Qxx08Vyy	64

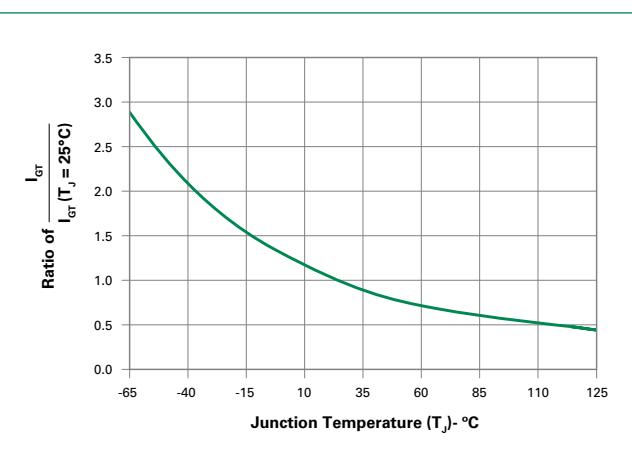
Note: xx = voltage/10, x = package, y = sensitivity, yy = type & sensitivity

Figure 1: Definition of Quadrants



Note: Alternistors will not operate in QIV

Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature



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Figure 3: Normalized DC Holding Current vs. Junction Temperature

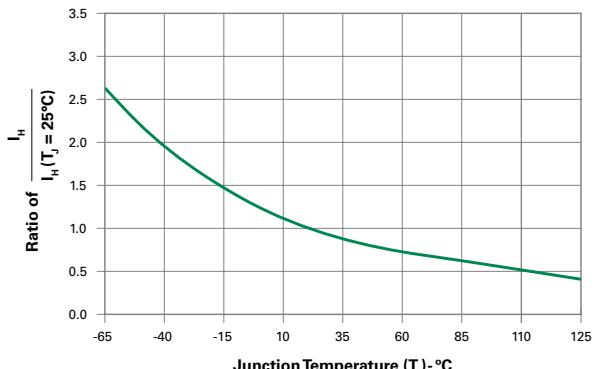


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

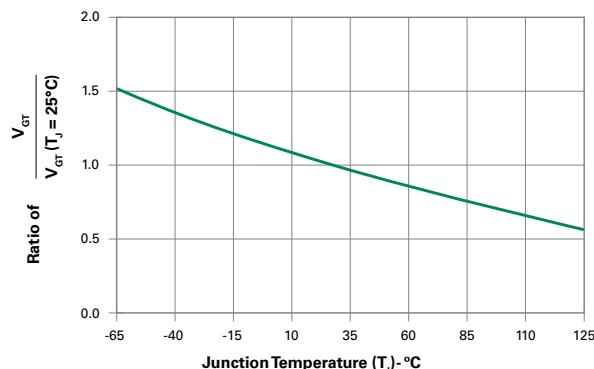


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

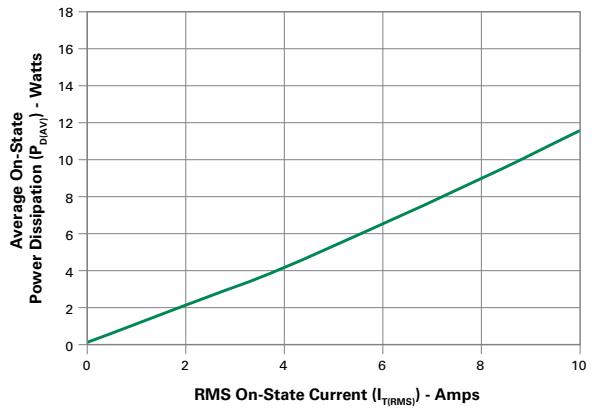


Figure 6: Maximum Allowable Case Temperature vs. On-State Current (Sensitive Triac)

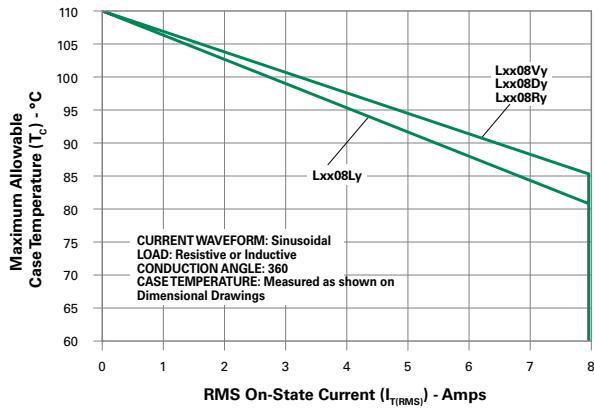


Figure 7: Maximum Allowable Case Temperature vs. On-State Current (Standard / Alternistor Triac)

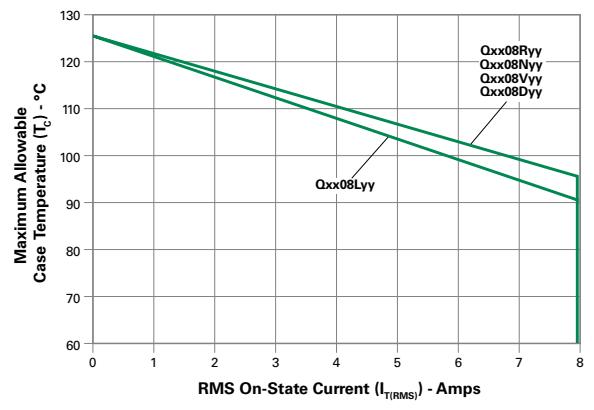
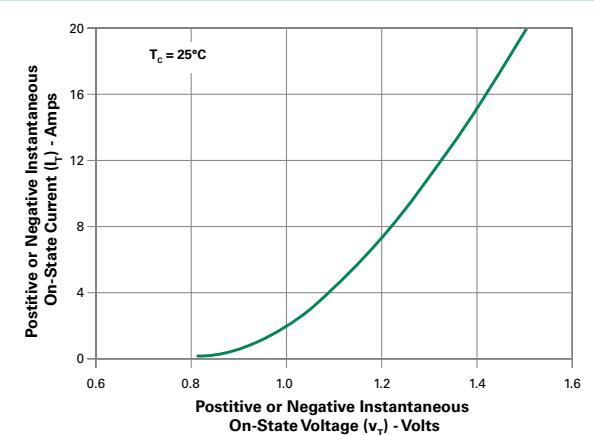


Figure 8: On-State Current vs. On-State Voltage (Typical)



Note: xx = voltage/10, x = package, yy = type & sensitivity

Figure 9: Maximum Allowable Ambient Temperature vs. On-State Current

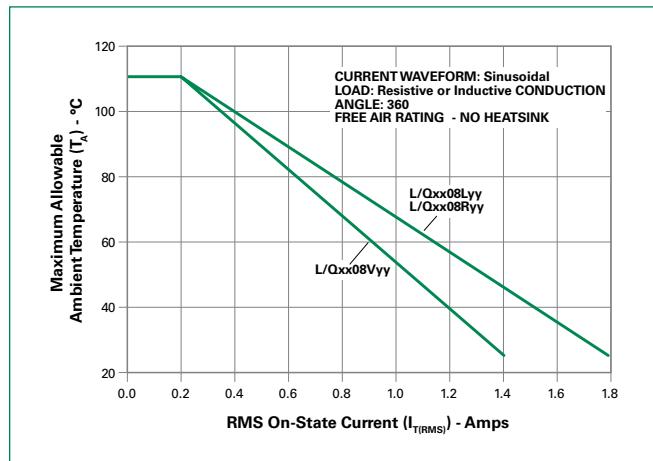
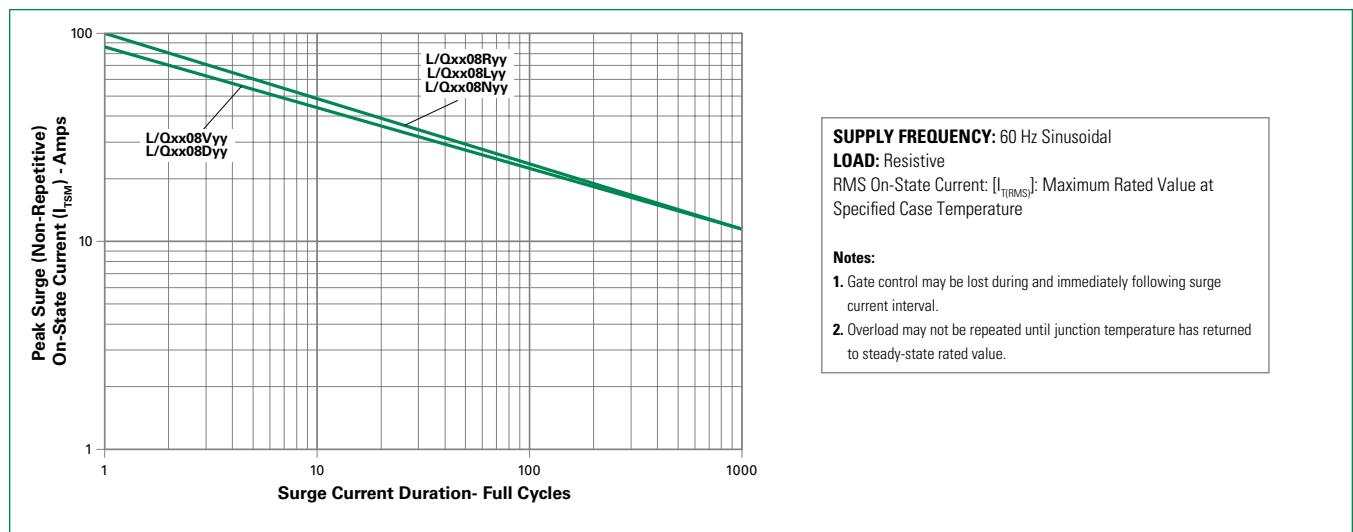


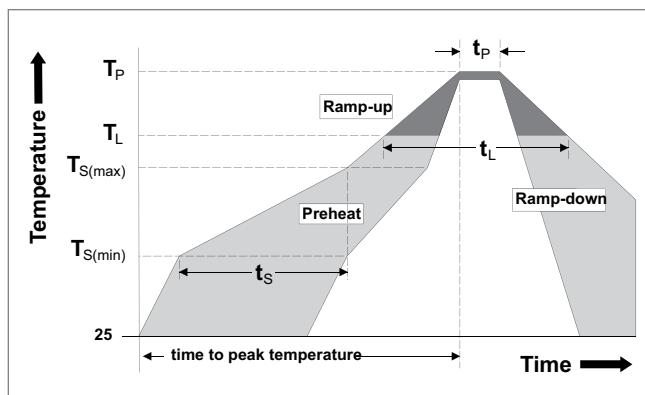
Figure 10: Surge Peak On-State Current vs. Number of Cycles



Note: xx = voltage/10, x = package, y = sensitivity, yy = type & sensitivity

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL Recognized compound meeting flammability rating V-0
Terminal Material	Copper Alloy

Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

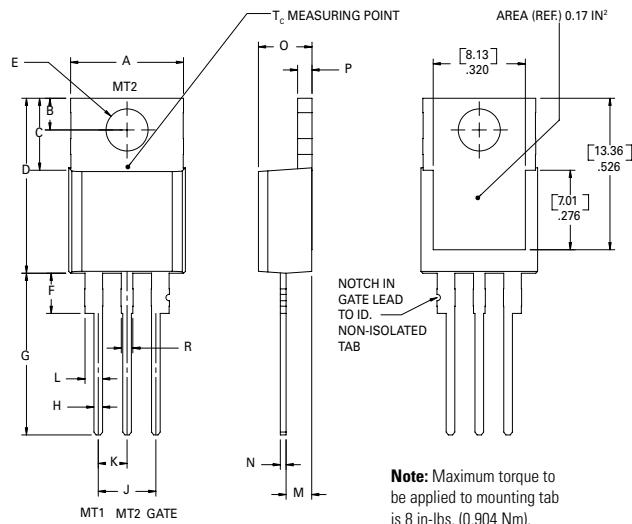
Environmental Specifications

Test	Specifications and Conditions
AC Blocking (V_{DRM})	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

Thyristors

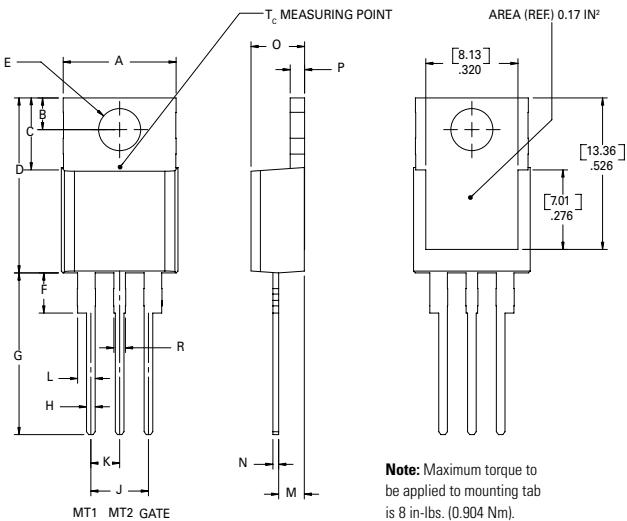
8 Amp Sensitive, Standard & Alternistor (High Commutation) Triacs

Dimensions – TO-220AB (R-Package) – Non-Isolated Mounting Tab Common with Center Lead



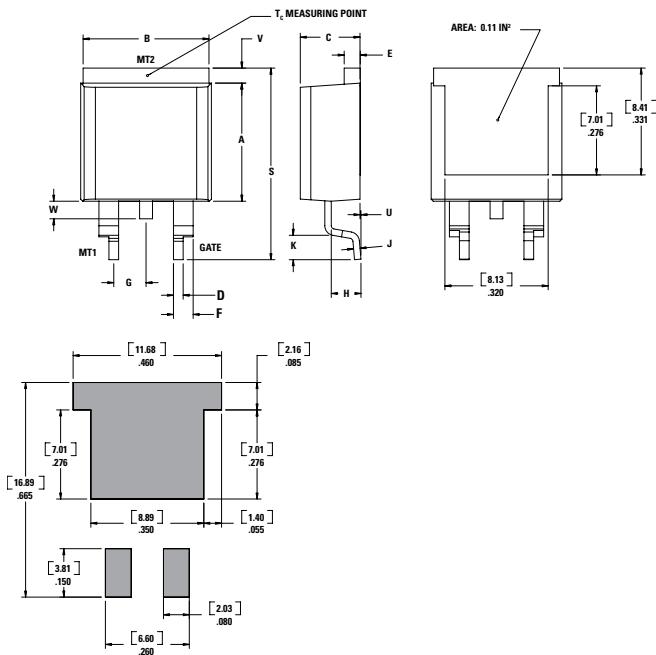
Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Dimensions – TO-220AB (L-Package) – Isolated Mounting Tab



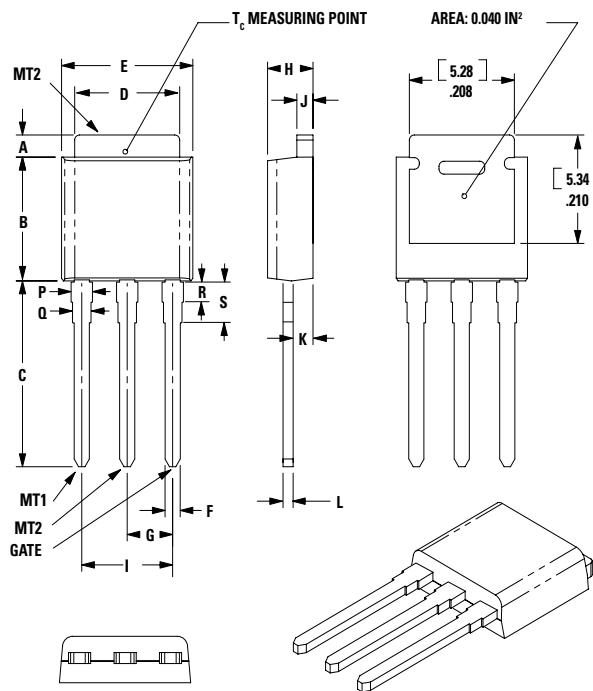
Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Dimensions — TO-263AB (N-Package) — D²-PAK Surface Mount



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.360	0.370	9.14	9.40
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
E	0.045	0.060	1.14	1.52
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
H	0.092	0.102	2.34	2.59
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.88
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.02	1.78

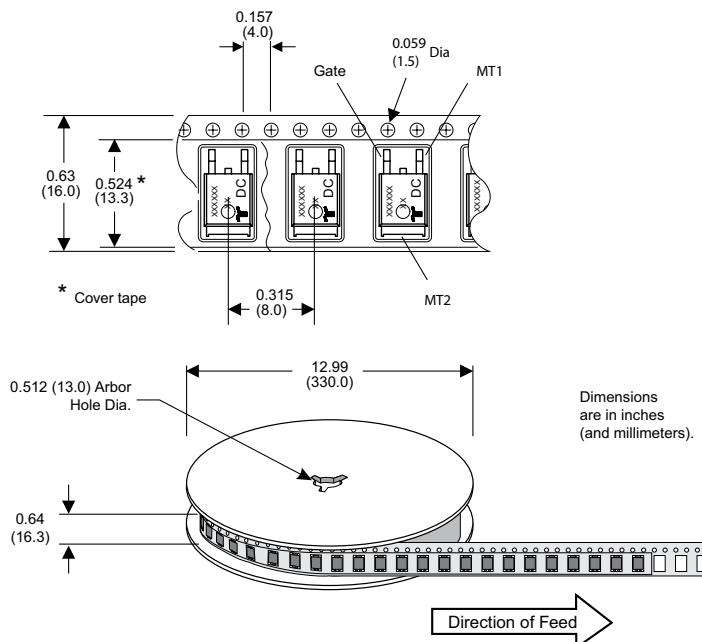
Dimensions — TO-251AA (V-Package) — V-PAK Through Hole



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.037	0.040	0.043	0.94	1.01	1.09
B	0.235	0.242	0.245	5.97	6.15	6.22
C	0.350	0.361	0.375	8.89	9.18	9.53
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.66	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.34	2.41
I	0.176	0.180	0.184	4.47	4.57	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.035	0.037	0.039	0.90	0.95	1.00
L	0.018	0.020	0.023	0.46	0.52	0.58
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11
R	0.034	0.039	0.044	0.86	1.00	1.11
S	0.074	0.079	0.084	1.86	2.00	2.11

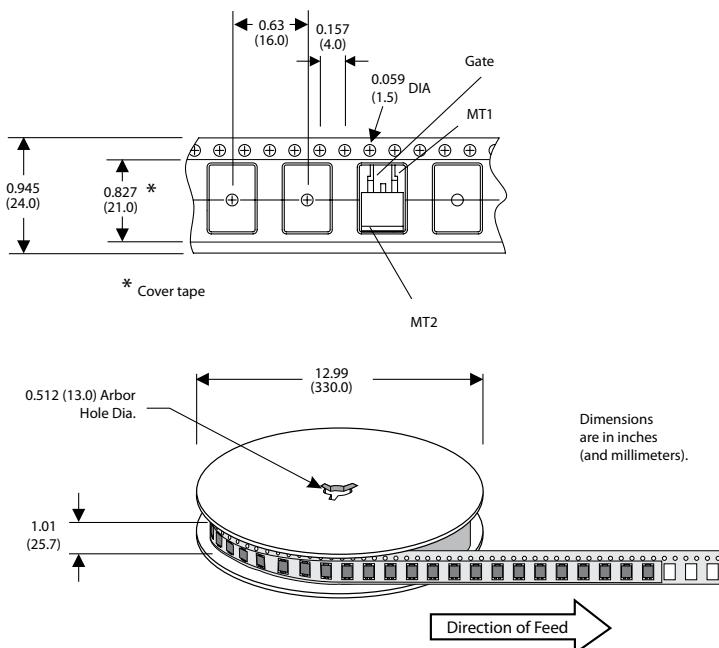
TO-252 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards

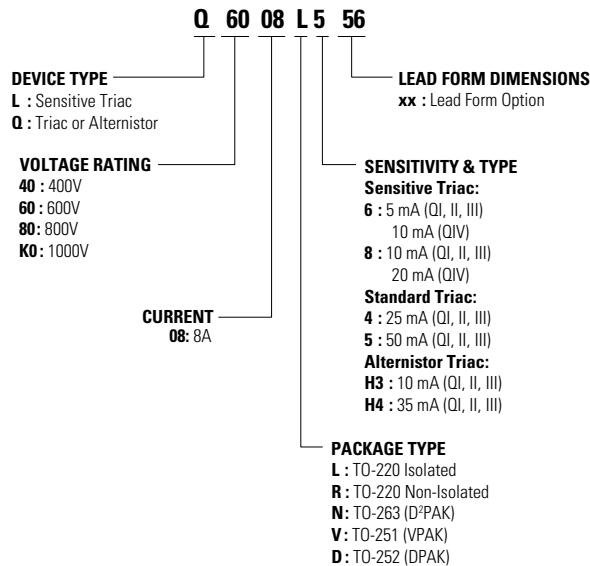


TO-263 Embossed Carrier Reel Pack (RP) Specifications

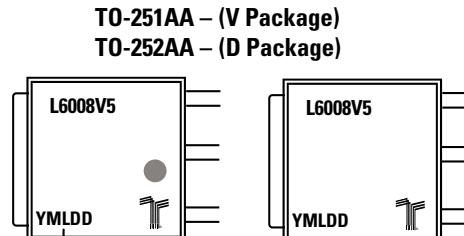
Meets all EIA-481-2 Standards



Part Numbering System

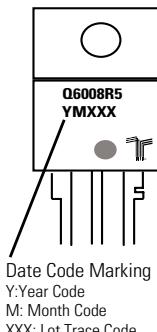


Part Marking System



Date Code Marking
 Y:Year Code
 M: Month Code
 L: Location Code
 DD: Calendar Code

TO-220 AB - (L and R Package)
TO-263 AB - (N Package)



Date Code Marking
 Y:Year Code
 M: Month Code
 XXX: Lot Trace Code

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Littelfuse:

L4008L8 L6008L8 Q2008R4 Q2008L4 Q4008L4 Q4008LH4 Q2008LH4 Q6008LH4 Q8008R5 Q6008LH453
Q6008VH4 Q6008LH458 Q8008DH3 Q4008L455 Q4008L458 Q8008LH4 Q4008DH4 Q6008DH4 Q4008DH3
QK008DH3 QK008DH4 Q8008L5 Q6008R5 Q6008L5 QK008LH4 QK008R5 Q4008RH467 L4008L6 Q4008VH3
Q4008R4 QK008L5 L6008L655 Q8008VH3 Q6008R559 L4008L656 L2008L6 L2008L8 Q4008VH4 Q6008L559
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